



Beam Condition Monitor for the CMS

BCM Group

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Beam Condition Monitor for CMS

Purpose

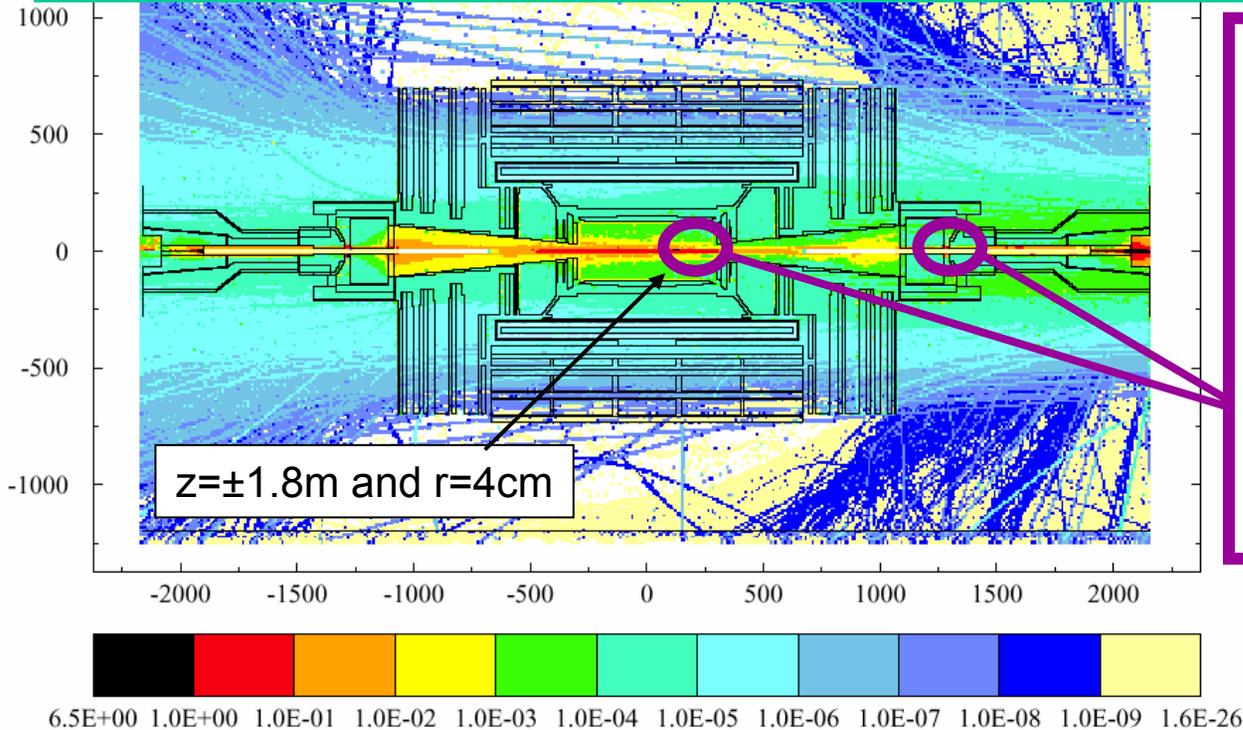
- The Beam Condition Monitor (BCM) has to provide online radiation monitoring within the CMS
- BCM forms part of the radiation monitoring system for equipment safety and radiation level/beam monitoring
- The BCM should be in addition to the LHC machine protection system and Beam Loss Monitors

BCM Issues

- Allows protection of equipment during instabilities/accidents
- Provides fast feedback to the machine for optimization of beam conditions
- Provides fast feedback to the machine for detection of adverse beam conditions
- Monitors the instantaneous dose during operation
- Provides input into LHC beam abort system (1 input/ experiment)

Accident Scenarios

Unsynchronised beam abort: $\sim 10^{12}$ protons lost in IP 5 in 260ns



Beam condition monitors

Looking for increase over normal rate

Monitors to be within CMS and feed to machine interlock

Sensors to be placed in the Pixel volume and after the Forward calorimeter

- Sensors under investigation: Polycrystalline Diamond
 - Fast signal response
 - Radiation hardness
 - Minimal services required ie no cooling necessary

Evaluated using a fast extraction beam from the CERN PS at the T7 beamline (November 2003)

Beam Accidents

What are the timescales

List of machine-identified equipment failures

Name	Operation Mode	Loss Location	ΔT
D1 warm	Collision	Triplet/collimator	5 turns
Damper	Injection	Arc/triplet	6 turns
Warm quadrupoles	Any	Collimator	18 turns
Warm orbit corrector	Collision	Triplet/collimator	55 turns
RF	Any	Arc/triplet/septum	55 turns
D1 warm	Injection	Arc/triplet/collimator	120 turns

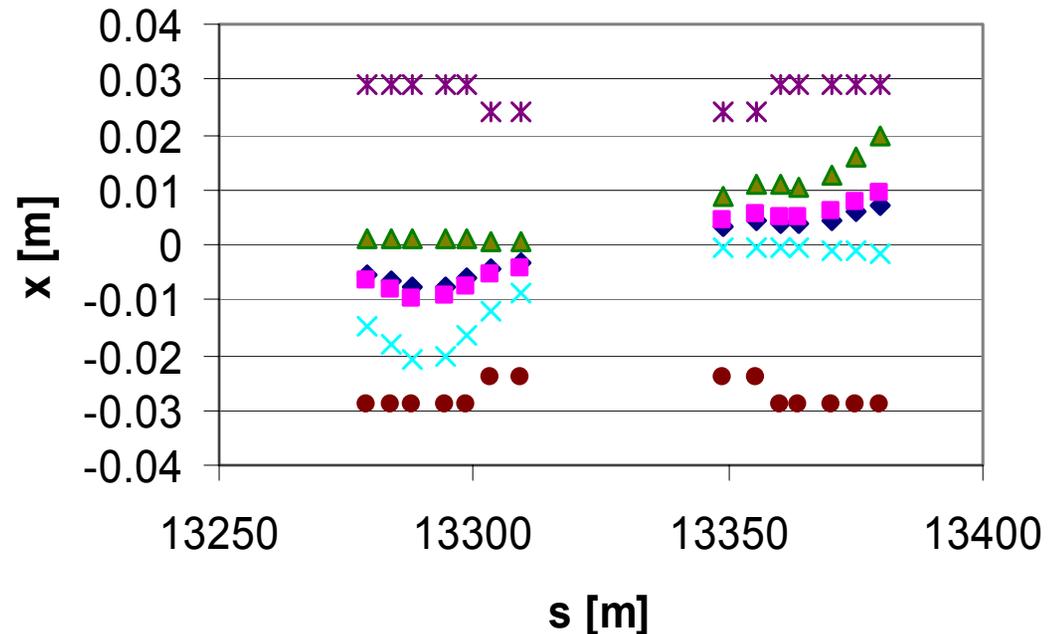
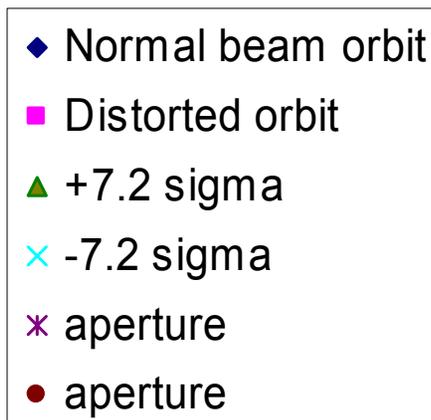


Fastest generic beam loss scenarios: ~ in 5 orbits ie ~ 500 μ s the beam is off by 3 sigma, this defines the response timescale of our system.

Beam Accidents

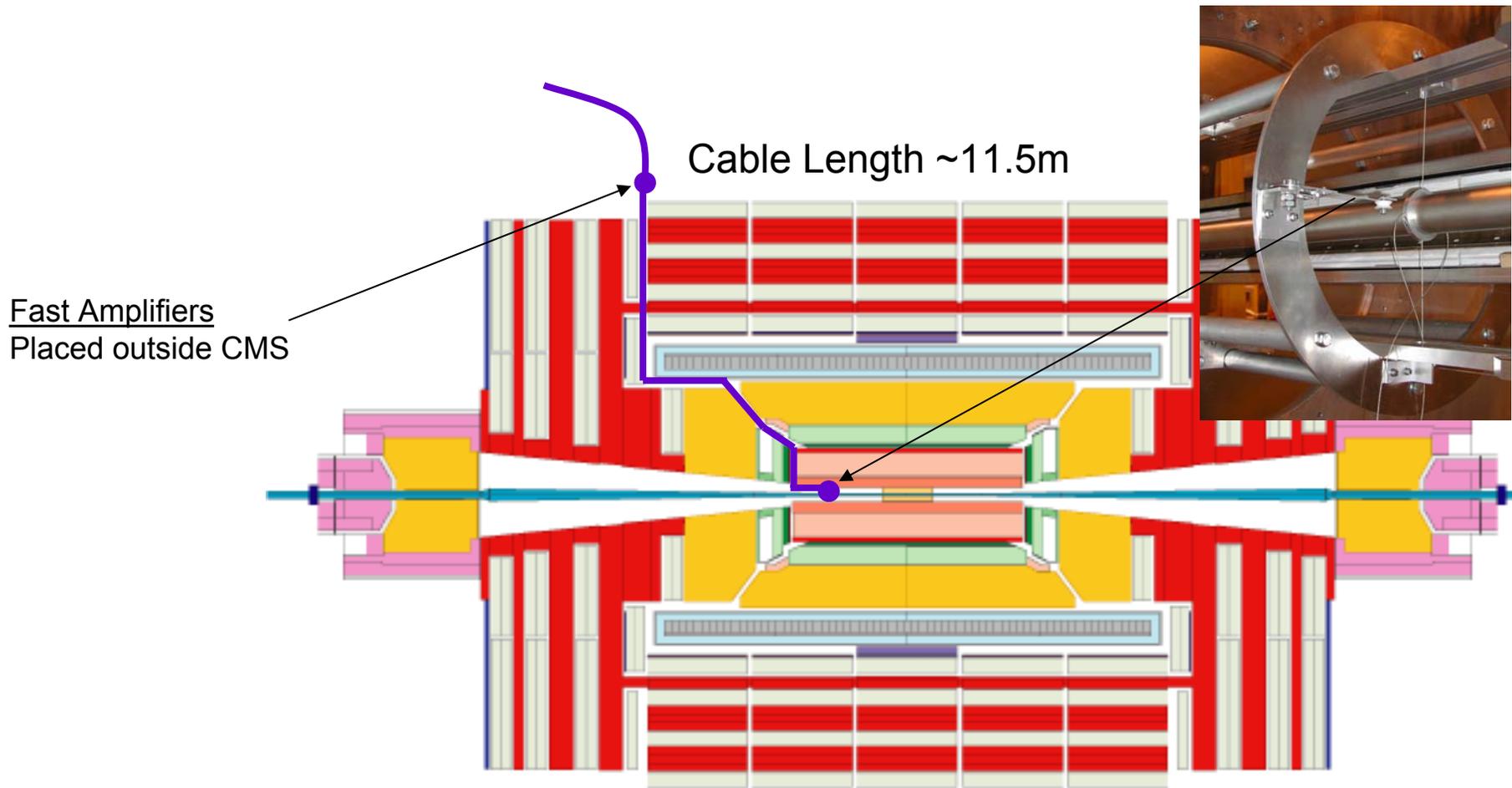
What are the timescales

After 15 turns



A MAD simulation for a D1 failure (by V. Kain) will serve us to calculate the numbers of protons that will be lost per turn. Then a Fluka simulation can give us the dose per turn that will allow us to set the timescales and the thresholds.

Conceptual BCM layout



DCS

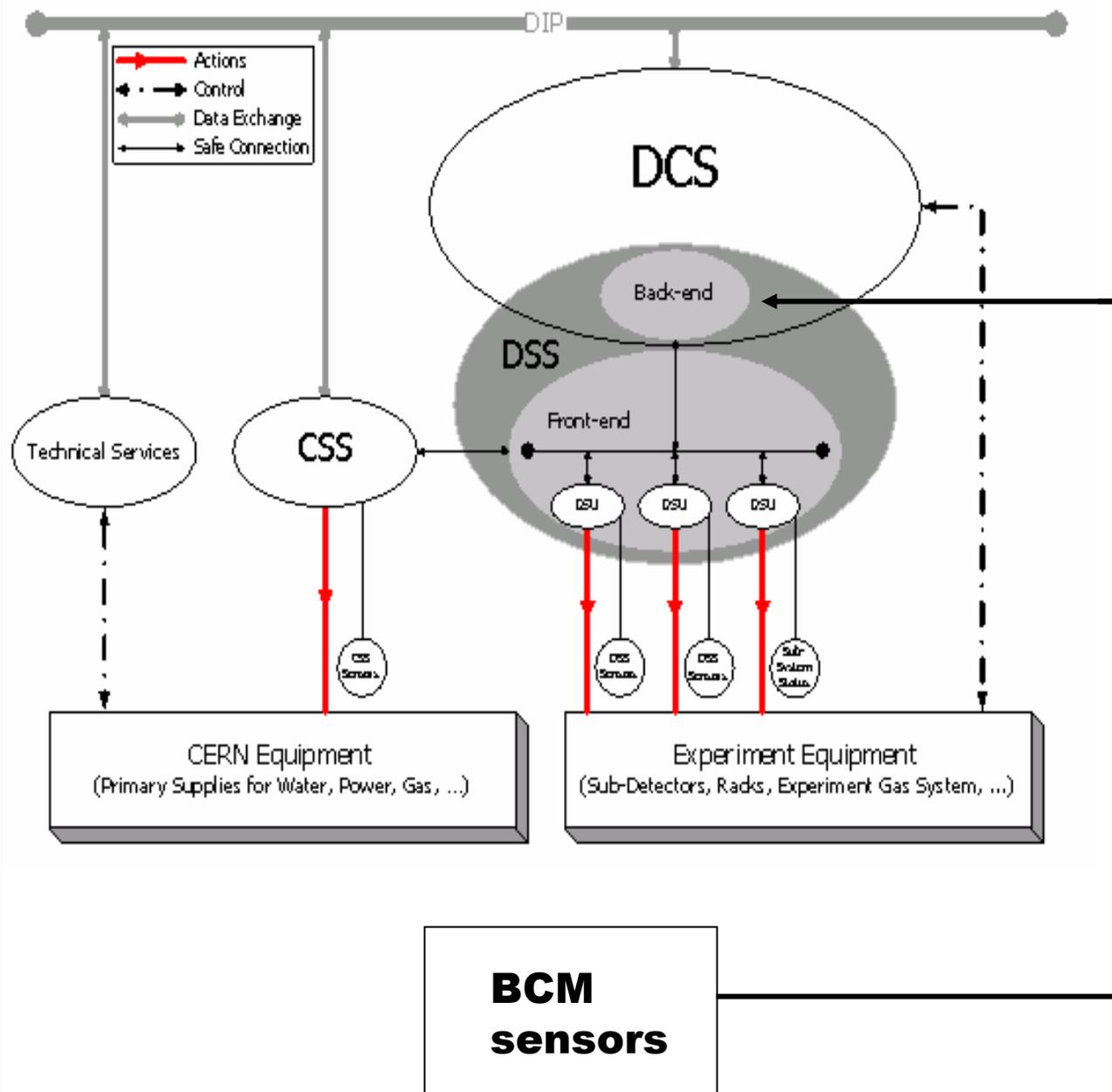
Monitoring and control of the detector

DSS

Safeguard of experimental equipment

BCM

- Input into DSS.
- Protect subdetectors from adverse beam conditions
- Redundant of the Beam Loss Monitors of the Machine



Diamond Characterization

Measurements performed on diamonds:

- I-V curve.

First quality check of the samples, metallisations.

To determine the electrical resistivity.

- Collection distance vs time.

Study of the pumping.

Charge collection distance at 1 V/ μm .

- Collection distance vs bias voltage.

Measurement of the charge collection distance at different electric fields.

Study of the radiation damage.

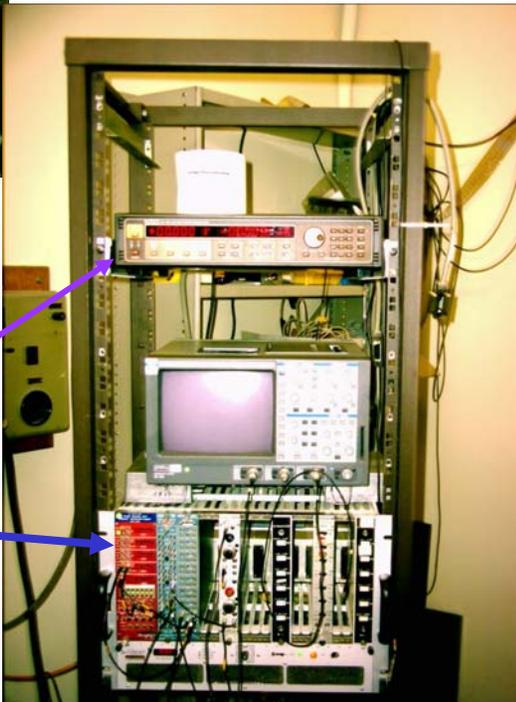
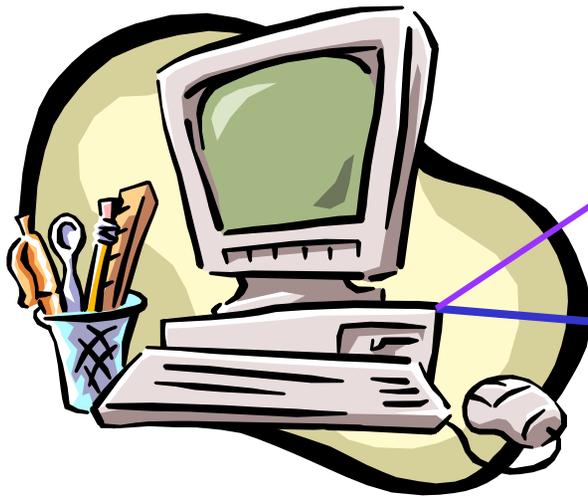
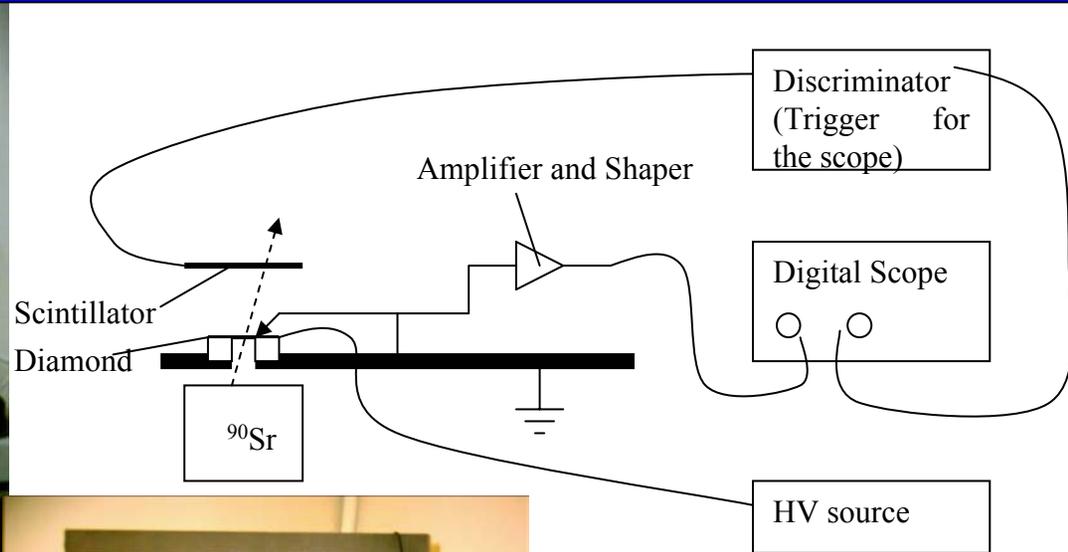
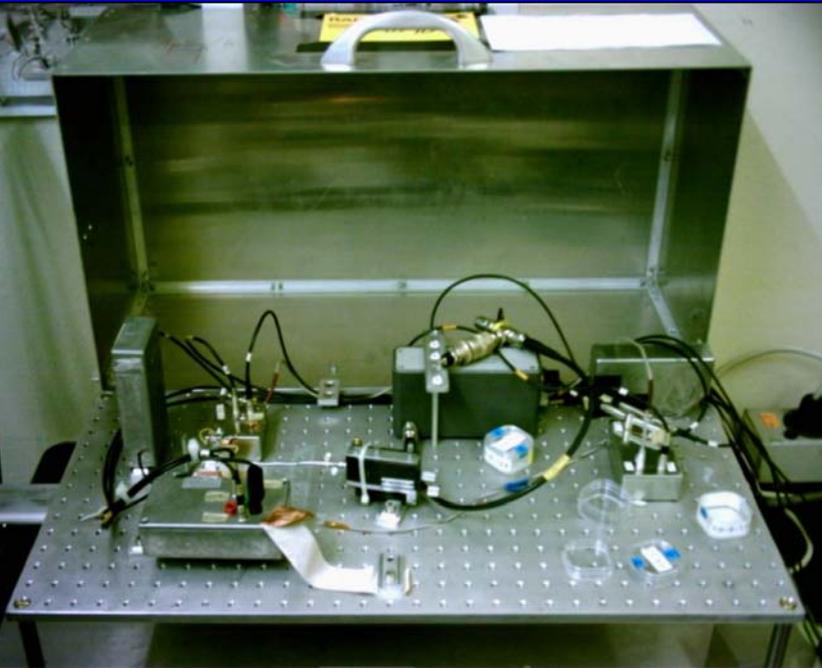
Study of the polarization.

- I-T curve.

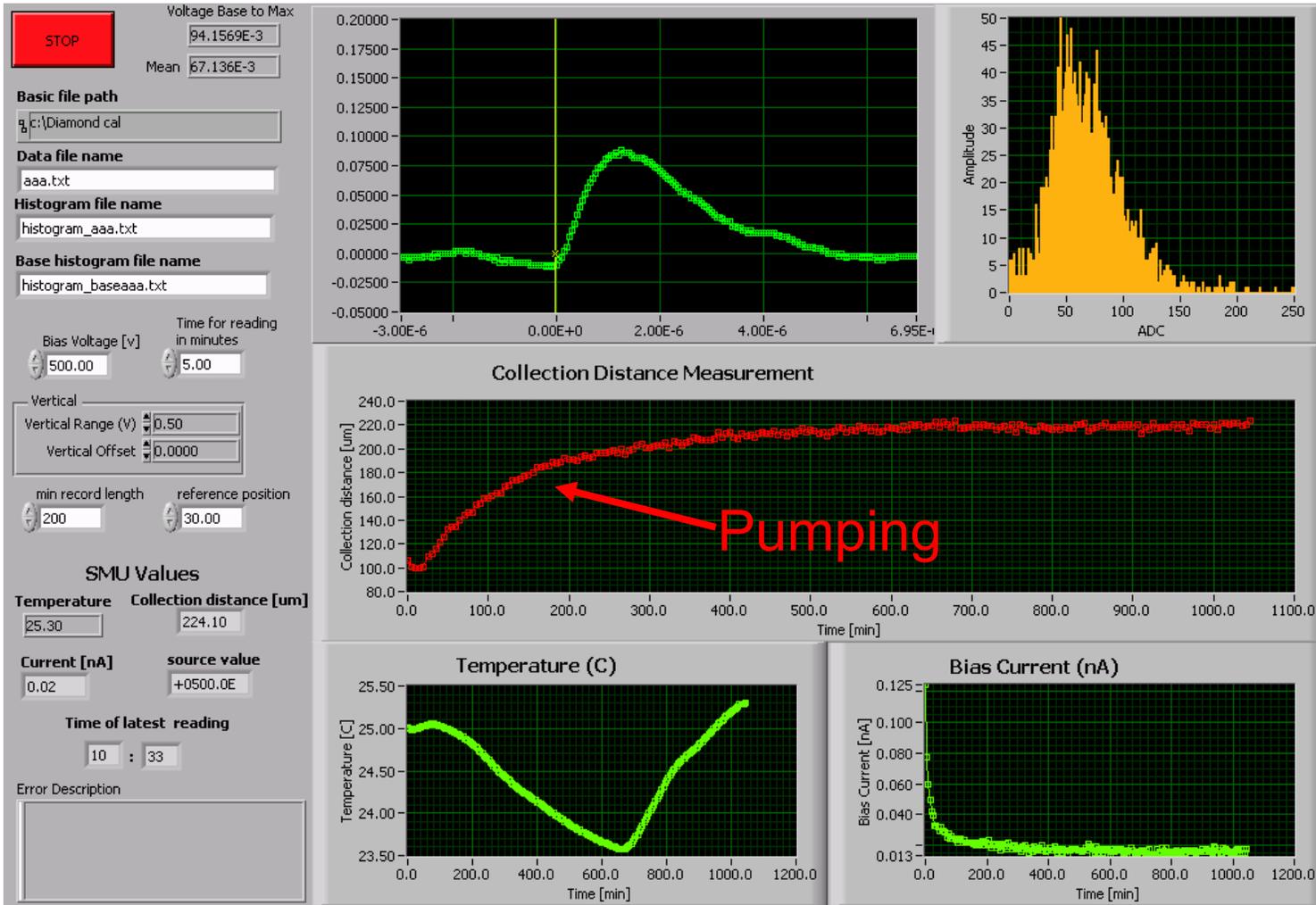
Find the thermo-stimulated current peak. Number of traps.

Depumping of diamonds.

Diamond Characterization



Diamond Characterization



The software gets the top value of the peak and deducts the average value of the base

Those values are averaged over a certain time (usually 5 min) for calculating the collection distance

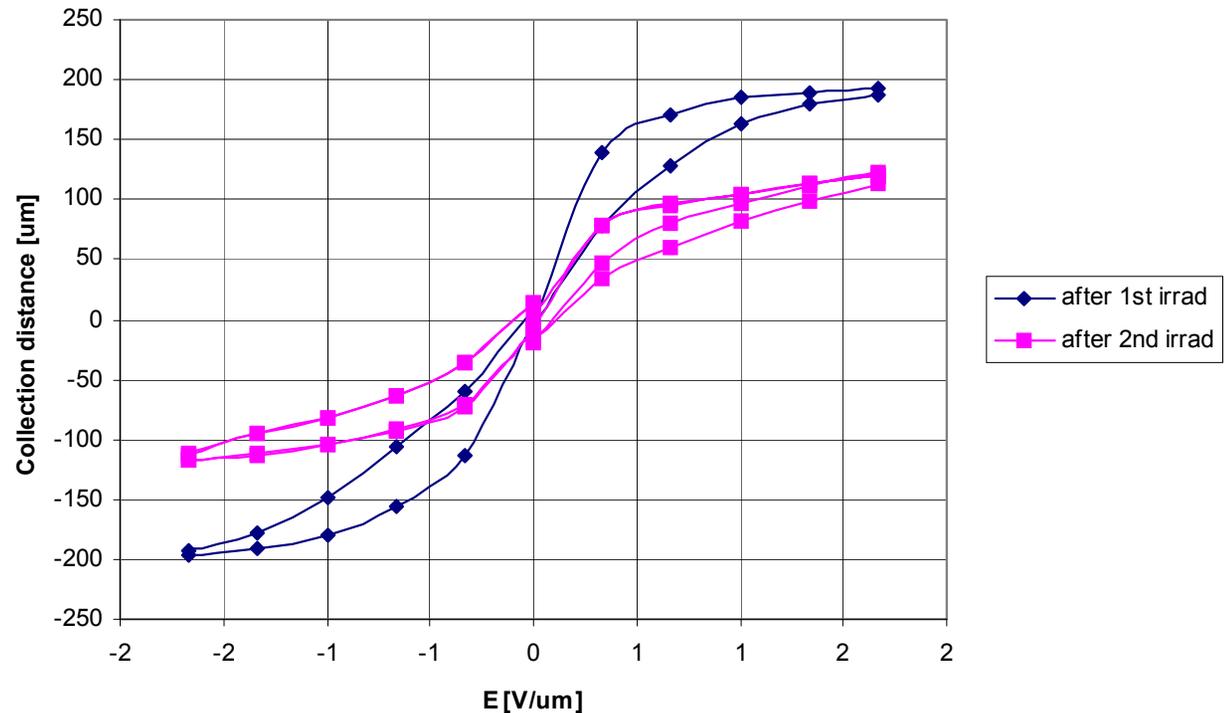
Study of the radiation damage

Collection distance vs
electrical field for an
irradiated diamond:

1st irradiation of $5E14$
 p/cm^2

2nd irradiation of $1E15$
 p/cm^2

The hysteresis observed
is due to a charge
polarization effect.

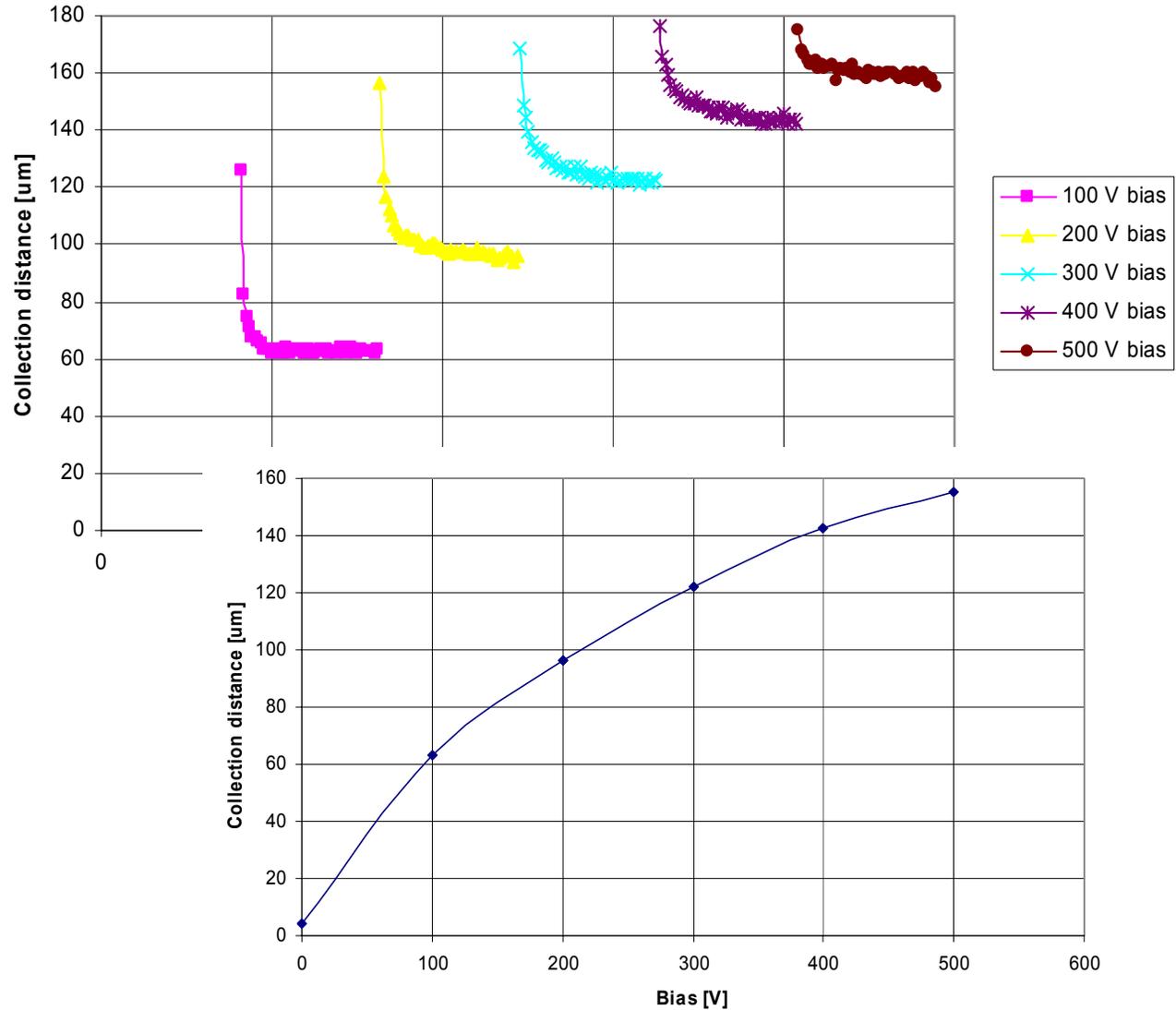


Measurement of the charge collection distance - Study of the polarization

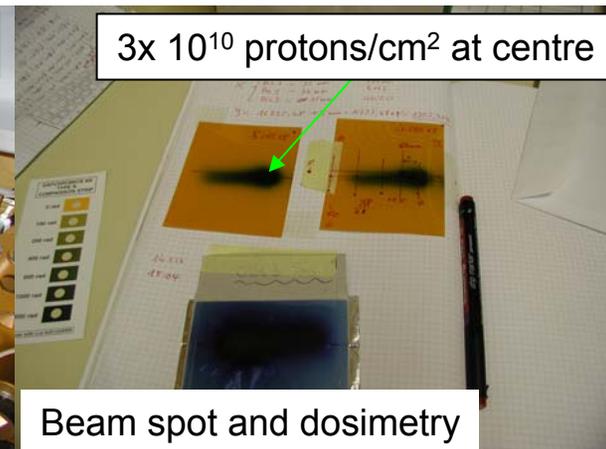
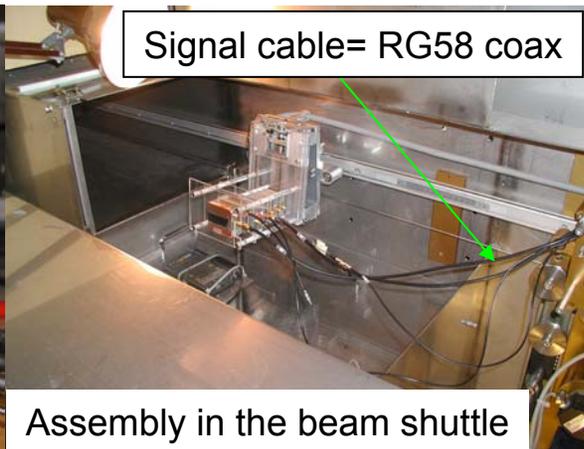
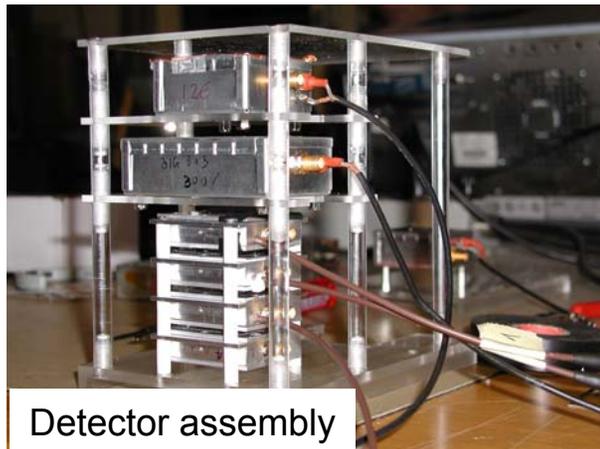
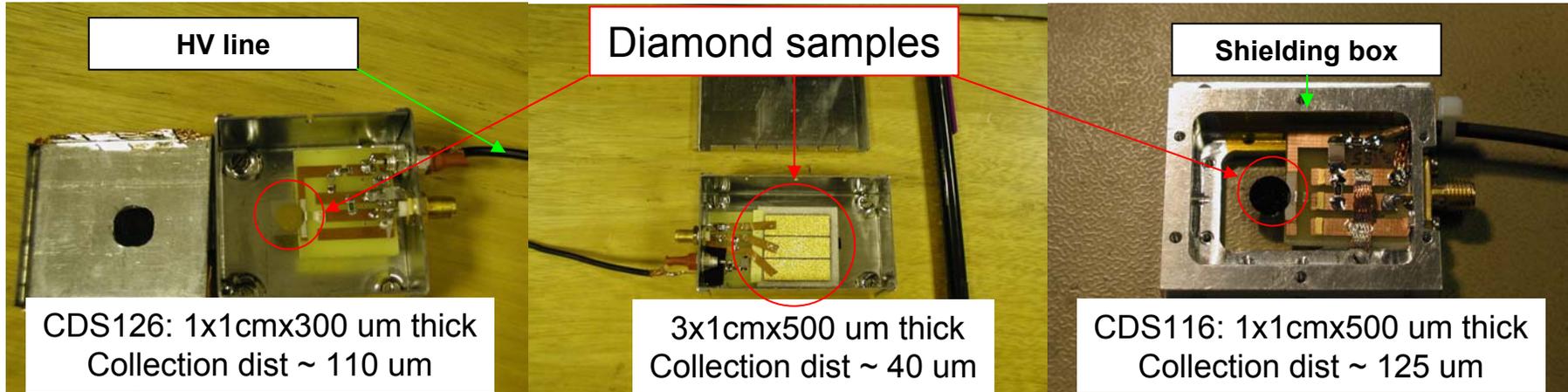
Polycrystalline diamond presents a polarization effect every time a bias voltage is applied to it.

The polarization appears any time the bias is increased.

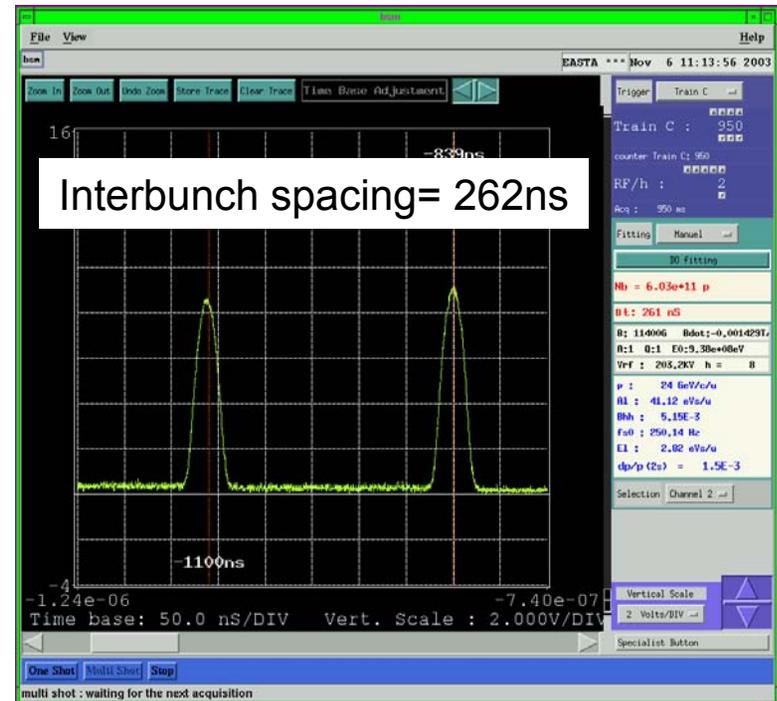
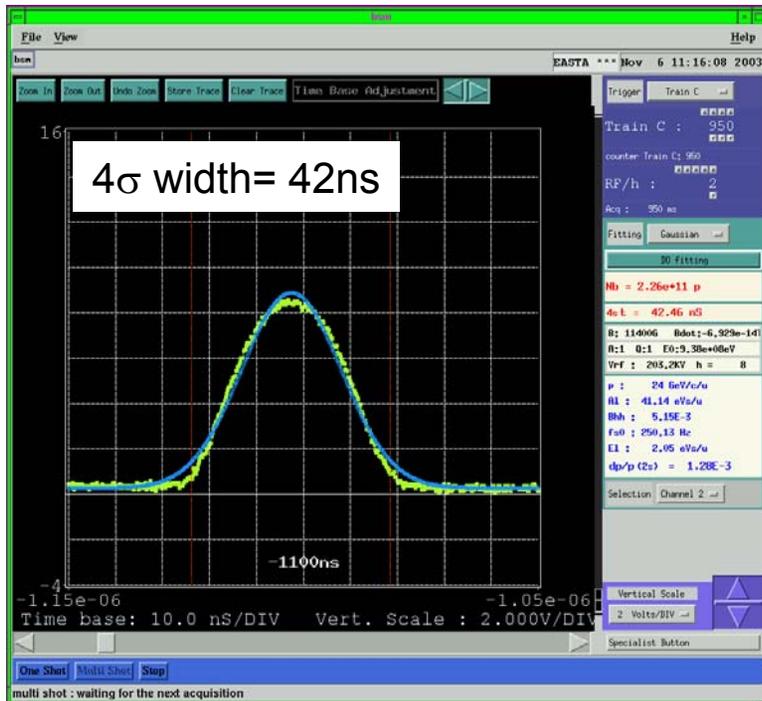
This graphic shows the “real” values of the collection distance (after polarization) at different electrical fields, after 4 hours.



T7 Testbeam Hardware



November T7 Test beam: Fast extraction beam from the PS



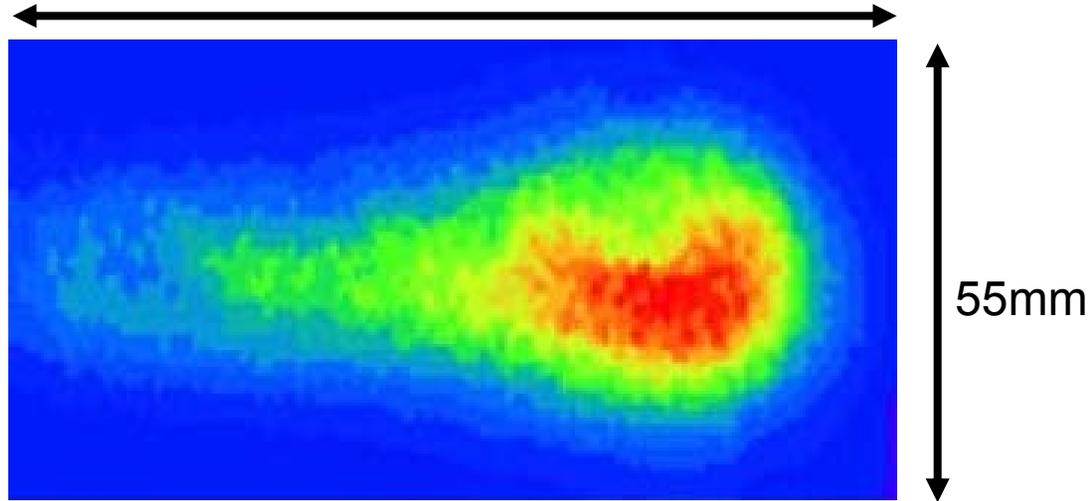
Beam intensity: 8×10^{11} protons per spill

Fluence: $\sim 3 \times 10^{10}$ protons/cm²/spill at the centre of the beam spot

$\sim 1 \times 10^8$ protons/cm²/spill in the halo

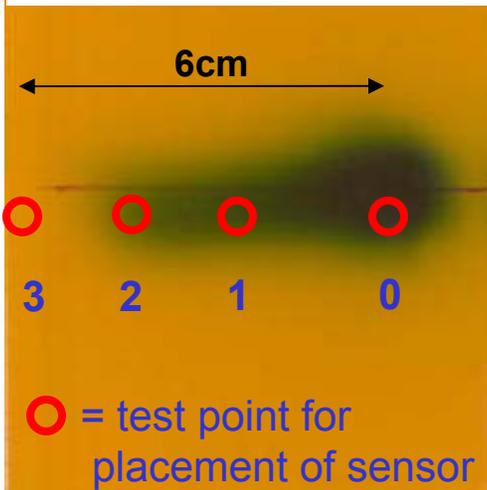
Beam profile

90 mm



Beam Profile as measured by OSL film
OSL = Optically Stimulated Luminescence

Film exposure of the beam after 40 bunches



Relative fluence levels

Position 0 = 1.0

Position 1 ~ 0.4

Position 2 ~ 0.2

Position 3 ~ 0.01

mm	0	5	10	15	20	25	30	35	40	45	50	55	60	65	70	75	80	85	90
0	0.2	0.2	0.2	0.2	0.3	0.2	0.0	0.0	0.0	0.0	0.0	0.0	0.0	0.1	0.1	0.1	0.1	0.1	0.0
5	0.2	0.2	0.2	0.3	0.3	0.3	0.1	0.3	0.4	0.8	0.7	1.0	1.0	1.4	1.3	1.2	1.0	0.1	0.1
10	0.6	0.6	0.6	0.8	0.9	0.9	0.8	0.8	1.0	1.0	1.1	1.3	1.5	2.1	2.0	2.0	1.6	0.2	0.1
15	0.6	0.6	0.6	0.8	1.1	1.1	1.3	1.1	1.4	1.6	1.8	2.3	2.6	3.5	3.0	2.9	2.7	0.2	0.1
20	0.7	0.7	0.7	1.1	1.4	1.7	1.9	2.1	2.8	3.2	4.9	5.0	7.7	9.8	12.7	10.6	6.2	0.5	0.1
25	0.7	0.9	0.9	1.0	1.5	3.1	7.4	10.3	13.1	15.6	17.6	21.5	26.7	38.9	56.7	45.0	17.7	1.2	0.1
30	0.7	0.9	0.8	1.1	2.2	7.4	18.6	28.4	28.9	39.3	45.6	48.9	70.8	82.1	100	87.8	36.5	4.3	0.2
35	0.7	0.8	0.9	1.1	2.7	6.1	17.4	25.1	28.5	34.4	27.7	42.4	42.2	61.1	58.1	69.2	28.1	6.1	0.2
40	0.6	0.7	0.8	1.1	2.2	4.1	6.6	8.1	8.5	8.6	10.3	13.5	18.7	26.7	36.0	28.3	10.5	3.4	0.2
45	0.6	0.7	0.7	0.8	1.1	1.9	2.2	1.7	1.7	2.7	3.1	4.3	5.8	7.6	8.1	5.7	4.0	2.4	0.2
50	0.7	0.6	0.7	0.9	0.8	1.0	1.2	1.1	1.3	1.5	1.6	2.2	2.2	2.6	3.1	2.6	2.3	1.8	0.1
55	0.4	0.5	0.6	0.7	0.8	0.8	0.8	0.7	0.8	1.1	1.0	1.1	0.7	0.6	0.4	0.4	0.3	0.2	0.1

Dosimetry measurements

Beamspace Dosimetry

Used ^{24}Na for dosimetry on aluminum placed in the beam

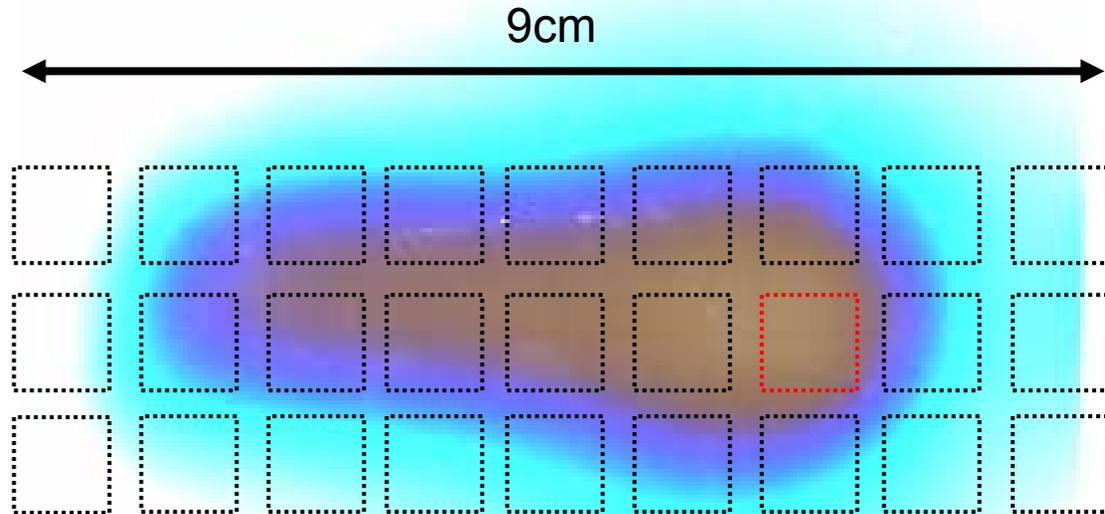
Dosimetry done by Maurice Glaser and Federico Ravotti

Result

Fluence at beam “centre” =
 2.8×10^{10} protons/cm $^2 \pm 10\%$

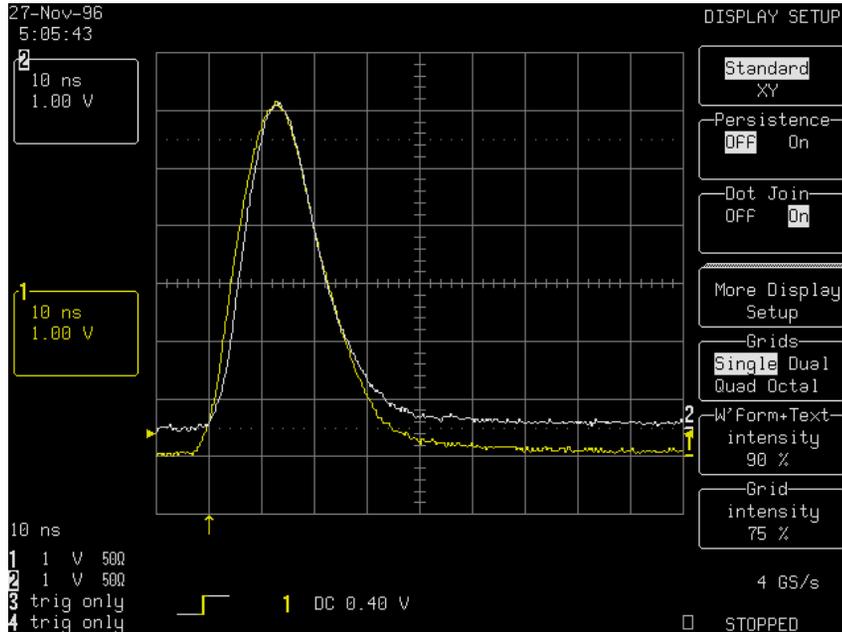
Mapping of beam spot

Consistency between the different films, the OSL, and the aluminum



Dosimetry Results from Grid of Aluminum samples: Relative variation %								
0.0	3.3	10.2	13.8	16.5	27.7	33.1	0.0	0.0
1.3	5.3	11.9	19.1	31.8	74.2	100.0	63.0	0.0
0.0	0.0	0.0	0.0	3.4	8.0	6.2	0.0	0.0

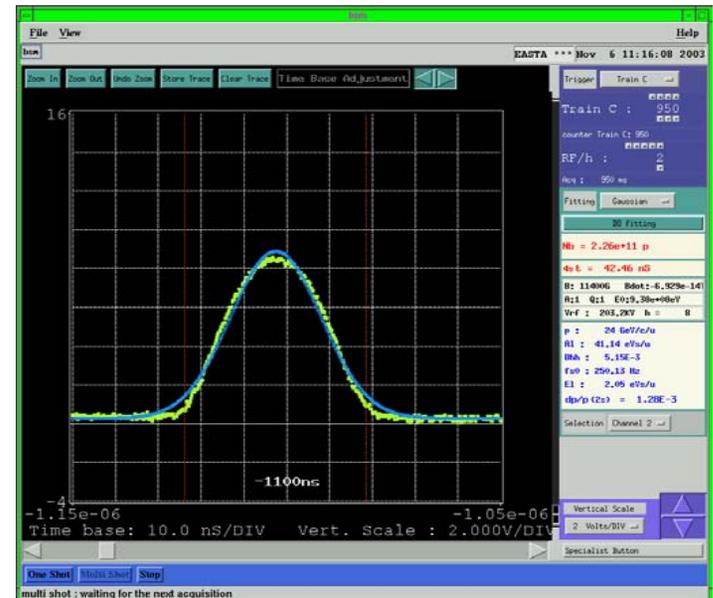
Single shots



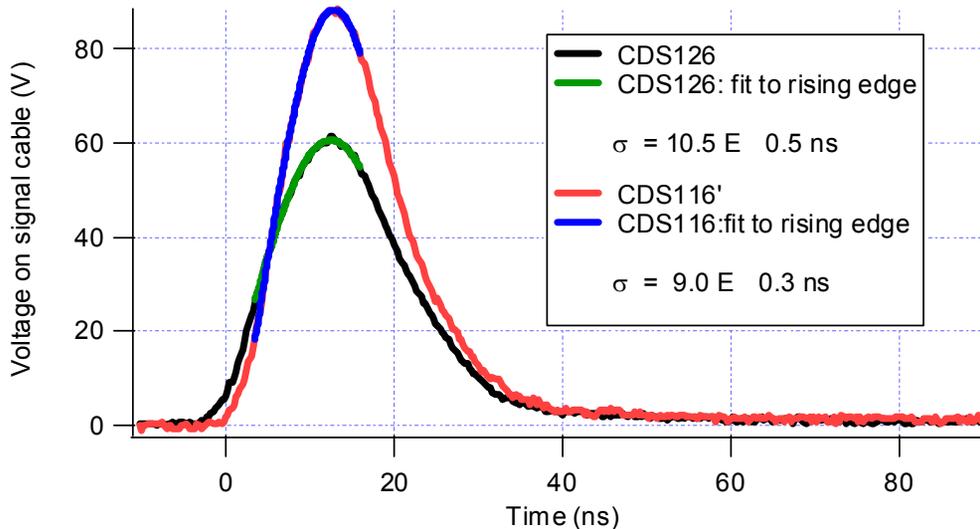
Almost identical to PS beam profile

Single pulses from diamond

- Bias on Diamond = $+1 \text{ V}/\mu\text{m}$
- Readout of signal:
 - 16m of cable
 - no electronics
 - 20dB attenuation on signal cable (factor 10)



Single shots: Details



Diamond Collection Distance

Diamond signal \sim collection distance

Collection distance (CDS116) $\sim 125 \mu\text{m}$

Collection distance (CDS126) $\sim 110 \mu\text{m}$

For std bias voltage of $1 \text{ V}/\mu\text{m}$

Area of pulse

- Proportional to current from a bunch.
- Use area to estimate bunch fluence.
 - Pulse area(CDS116@Pt 3) = $9.8 \times 10^7 \text{ p}/\text{cm}^2$
 - Pulse area(CDS126@Pt 3) = $8.7 \times 10^7 \text{ p}/\text{cm}^2$
- Fair agreement with dosimetry results
 - Dosimetry(Al, @ Pt 3) = $2.2 \times 10^8 \text{ p}/\text{cm}^2$

Diamond Collection Distance

Signals from sensors are large

- V_{max} (CDS116) = 88 volts \Rightarrow 1.76 Amps into a 50 Ohm load
- V_{max} (CDS126) = 61 volts \Rightarrow 1.22 Amps into a 50 Ohm load

Time response

Fit Gaussian to leading edge of pulses

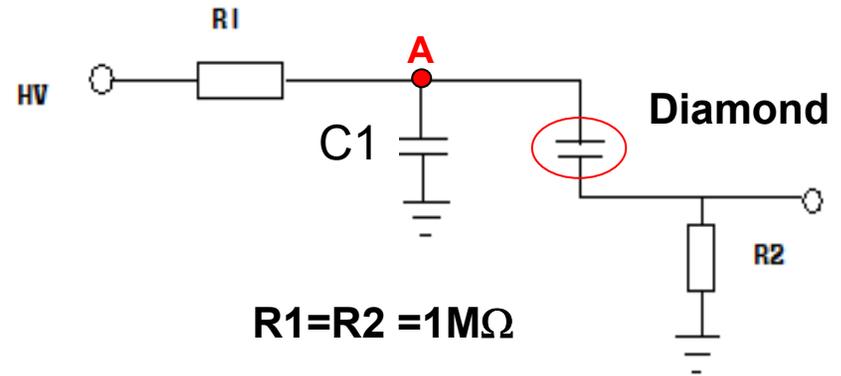
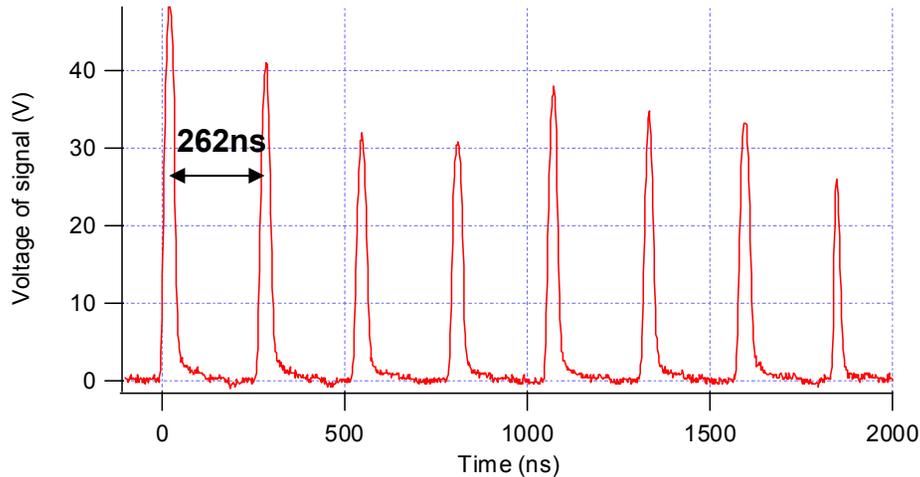
σ (CDS126) = $10.5 \pm 0.5 \text{ ns}$

σ (CDS116) = $9.0 \pm 0.3 \text{ ns}$

Comparable to $\sigma(\text{PS}) = 10.5 \text{ ns}$ with
 $\sim 6\%$ distortion from the signal cable

\Rightarrow No problem with extracting timing structure from sensors on 16 m coax cable

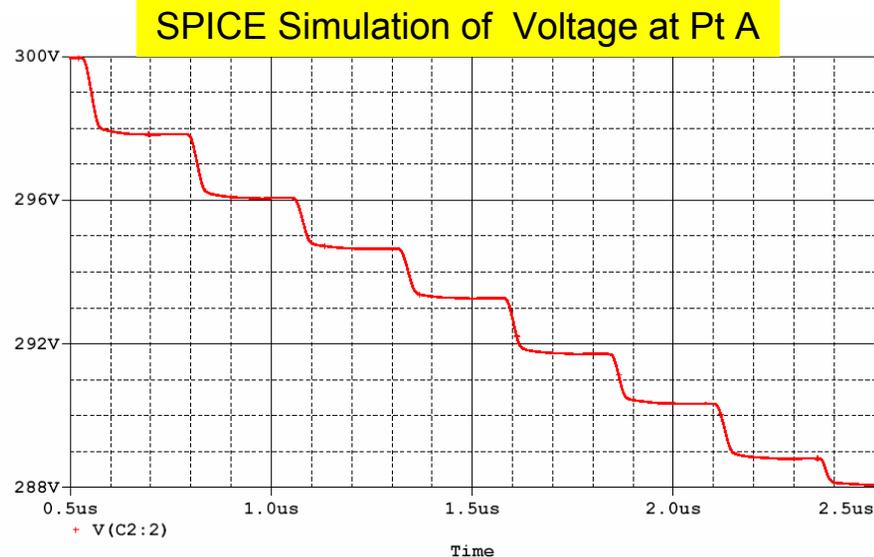
Multiple Bunches



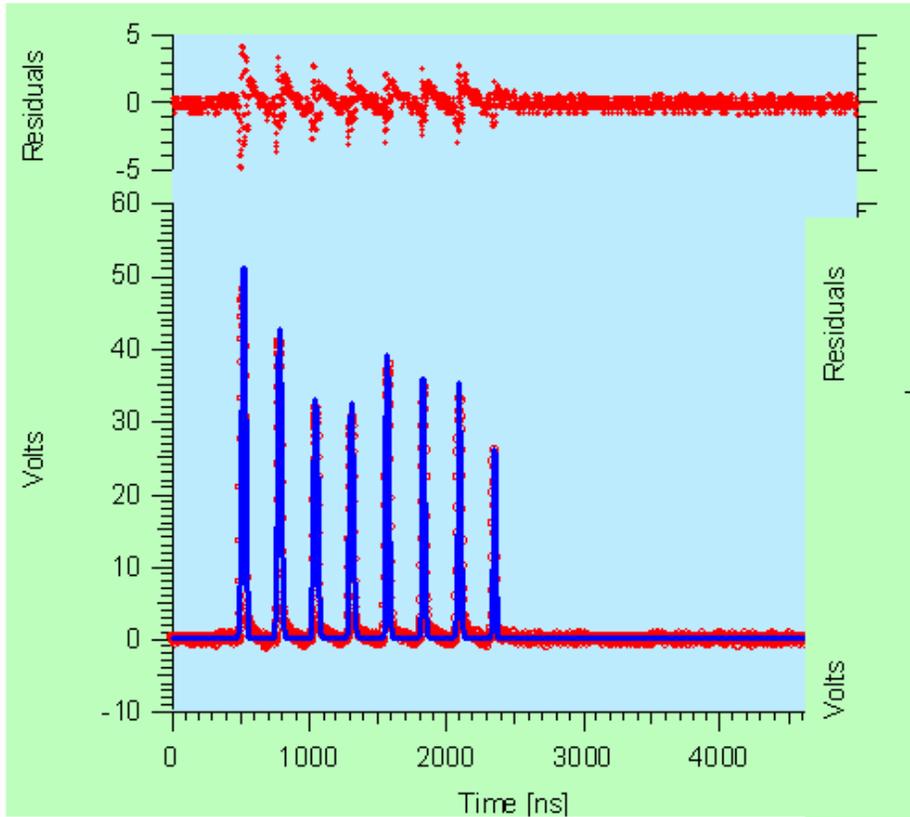
C1 acts as a reservoir capacitor
=>The larger the value the longer the bias field on the can be maintained.

C1(CDS126)=15 nF
C1 is sufficiently large to maintain bias across the diamond for the 8 bunches.

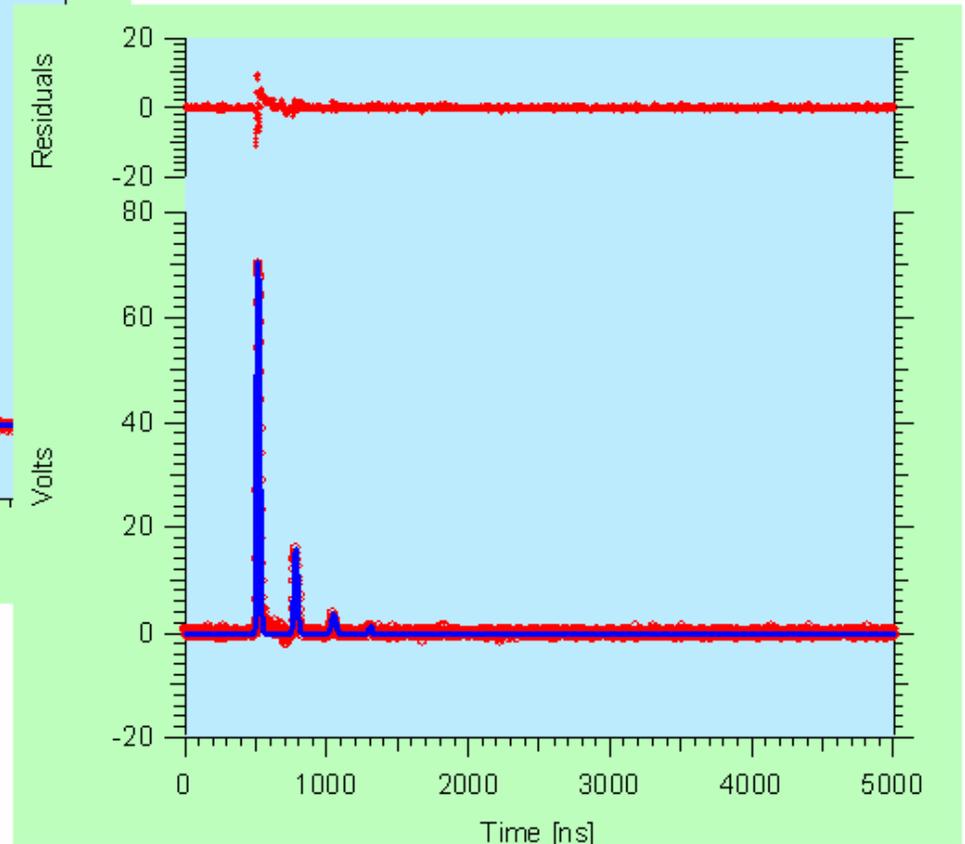
C1R1 time constant ~ 15 ms
 \Rightarrow recharge of C1 is slow compared to bunch structure



Multiple Bunches



CDS116 (125 μm @ 500V). The integration of the gaussian fit for the first peak gives a value of $1.2 \times 10^8 \text{p/cm}^2$



CDS126 (110 μm @ 300V). The integration of the gaussian fit for the first peak gives a value of $9.05 \times 10^7 \text{p/cm}^2$

Conclusions

- An automatic setup for measuring diamond characteristics has been developed.
- This setup allows detailed studies of diamond polarization effects.
- Diamonds are able to withstand intense beam.

Next Steps

- Finish analyzing the data that we have from the November testbeam:
 - Data taken is for the “worst case” scenario
- Build a prototype BCM (sensors+ electronics + decision logic)
 - Reduce signal to noise so to clearly see MIPs
- Continue with the characterization of diamonds
- May 04: Return to the East Hall for dedicated fast extraction beam
 - Intensity: 10^3 to 10^6 particle/cm²
 - Test prototype electronics
 - Evaluate BCM threshold-response time